



# Introduction to semiconductor devices for microwave applications

PMRF-ISSS082/V/2024

## Name of the PMRF student

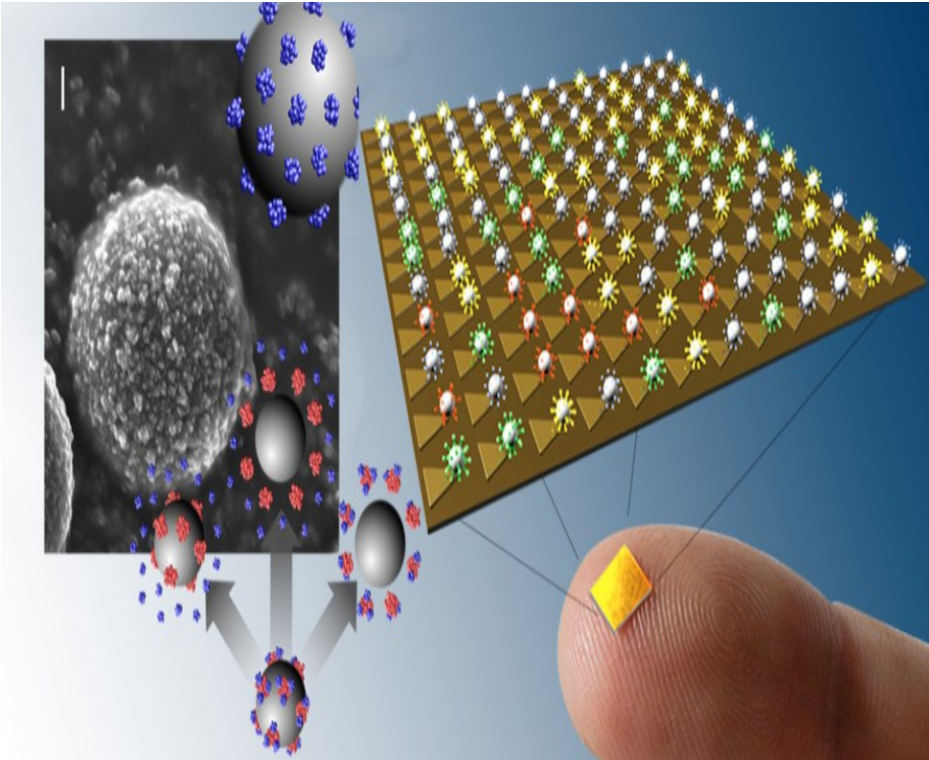
Mohammad Ateeb Munshi

## Required background of the students taught

Electronics, Electrical, Physics, Material Sciences

## Online session coordinator

Will be chosen from the list of registrants



## Details of the content of the module

### • Introduction to the course

Microwave spectrum, Microwave applications, Semiconductor devices for Microwave applications. Historical overview.

### • Heterojunctions

Introduction to Gallium Arsenide, Gallium Nitride Devices, Schottky Multipliers, Varactors.

### • Transfer electron Devices

IMPATT diodes, Gunn diode (working, physics)

### • III-V MESFETs

Physics, carrier transport, characteristics.

### • III-V HEMTs

Physics, 2DEG, breakdown, gain, dispersion

### • p-HEMTs

Recess gate, field plate, multifinger devices, power cell.

## Schedule of the module

Lectures will be uploaded on **Saturday** 8pm

Lectures will start from **10th June 2024 (Tentative)**

Course will end on September 10<sup>th</sup> 2024.

Course Hours: 26 Hours

## Link

Contact email ID: [issc.forum@gmail.com](mailto:issc.forum@gmail.com)

Registration link:

<https://forms.gle/7Ym1ejckHZY1G7tL6>